



JST06A TRIAC

Rev.A.1.1

DESCR

The JST06A triac is suitable for general purpose AC switch applications used as an ON/OFF function in applications such as heating regulation, induction motor starting and phase control operation in light dimmers and speed controllers. JST06A-600TW snubberless triac is specially recommended for use on induction loads. It can be driven directly through the MCU I/O port with an internal ceramic pad, JST06A-600TW provides a maximum off-state voltage of 2500 VRMS, complies with RoHS standards (File ref: E252906). Packaged in a 6-pin package, JST06A-600TW is RoHS compliant.

MAIN

Symbol	Value	Unit
I_T	6	A
V_{DRM}	600	V

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40-150	
Operating junction temperature range	T_j	-40-125	
Repetitive peak off-state voltage ($T_j=25^\circ C$)	V_{DRM}	600	V
Repetitive peak reverse voltage ($T_j=25^\circ C$)	V_{RRM}	600	V
RMS on-state current ($T_c=100^\circ C$)	$I_{T(RMS)}$	6	A
Non repetitive surge peak on-state current (full cycle, $t_p=20ms$, $T_j=25^\circ C$)	I_{TSM}	65	A
Non repetitive surge peak on-state current (full cycle, $t_p=16.6ms$, $T_j=25^\circ C$)		72	
I^2t value for fusing ($t_p=10ms$, $T_j=25^\circ C$)	I^2t	21	A^2s
Critical rate of rise of on-state current ($I_G=2 I_{GT}$, $f=100Hz$, $T_j=125^\circ C$)	di/dt	50	$A/\mu s$

Peak gate current ($t_p=20\mu s$, $T_j=125$)	I_{GM}	4	A
Average gate power dissipation ($T_j=125$)	$P_{G(AV)}$	0.5	W
Peak gate power	P_{GM}	10	W
Peak pulse voltage ($T_j=25$; non-repetitive, off-state; FIG.7)	V_{pp}	3.5	kV

ELECTRICAL CHARACTERISTICS ($T_j=25$ unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	$V_D=12V$ $R_L=33$	- -	MAX.	5	mA
V_{GT}		- -	MAX.	1	V
V_{GD}	$V_D=V_{DRM}$ $T_j=125$ $R_L=3.3k$	- -	MIN.	0.2	V
I_L	$I_G=1.2I_{GT}$	-	MAX.	10	mA
				15	
I_H	$I_T=100mA$		MAX.	10	mA
dV/dt	$V_D=400V$ Gate Open $T_j=125$		MIN.	150	V/ μs
$(dI/dt)_c$	$(dV/dt)_c=10V/\mu s$, $T_j=125$		MIN.	0.5	A/ms
t_{on}	$I_G=10mA$ $I_A=200mA$ $I_R=20mA$ $T_j=25$		TYP.	2	μs
t_{off}				20	

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX.)	Unit
V_{TM}	$I_{TM}=8.5A$ $t_p=380\mu s$	$T_j=25$	1.5	V
V_{TO}	Threshold voltage	$T_j=125$		

FIG.1: Maximum power dissipation versus RMS on-state current

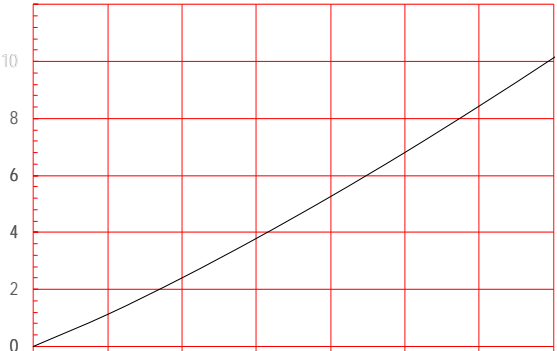


FIG.2: RMS on-state current versus case temperature

FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



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